

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

$I_{F(AV)}$ 5220A
 V_{RRM} 1100 ~ 2000V
 I_{FSM} 60 kA
 I^2t 18000 10³A²S

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T _j (°C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	$T_C=85^{\circ}C$				5220	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		175	1100		2000	V
I_{RRM}	Repetitive peak current	at V_{RRM}		175			200	mA
I_{FSM}	Surge forward current	10ms half sine wave		175			60	kA
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$						18000
V_{FO}	Threshold voltage			175			0.85	V
r_F	Forward slope resistance							0.069
V_{FM}	Peak forward voltage	$I_{FM}=5000A, F=40kN$		25			2.0	V
Q_{rr}	Recovery charge	$I_{FM}=2000A, tp=4000\mu s, di/dt=-20A/\mu s, V_R=100V$		175		5500		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. double side cooled					0.010	°C/W
$R_{th(c-h)}$	Thermal resistance case to heat sink	Clamping force 40kN					0.003	
F_m	Mounting force				35		47	kN
T_{vj}	Junction temperature				-40		175	°C
T_{slg}	Stored temperature				-40		175	°C
W_t	Weight					1100		g
Outline	P46a							

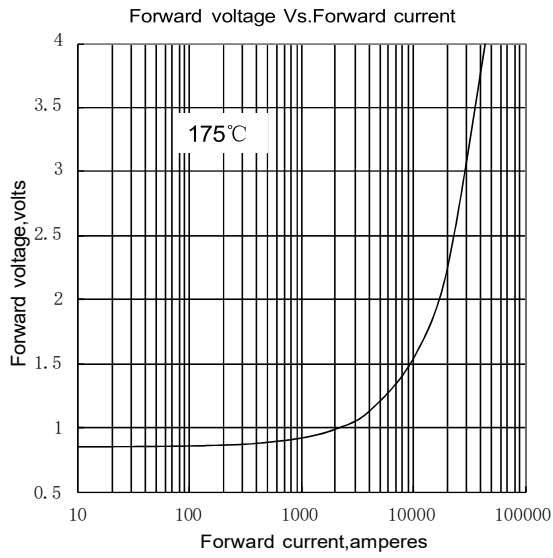


Fig.1

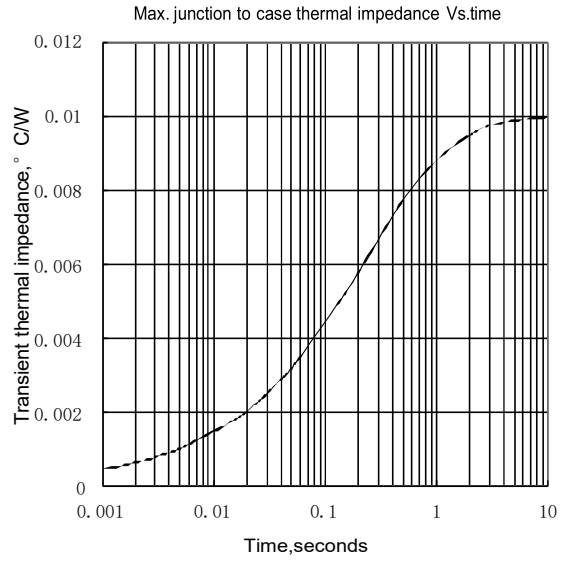


Fig.2

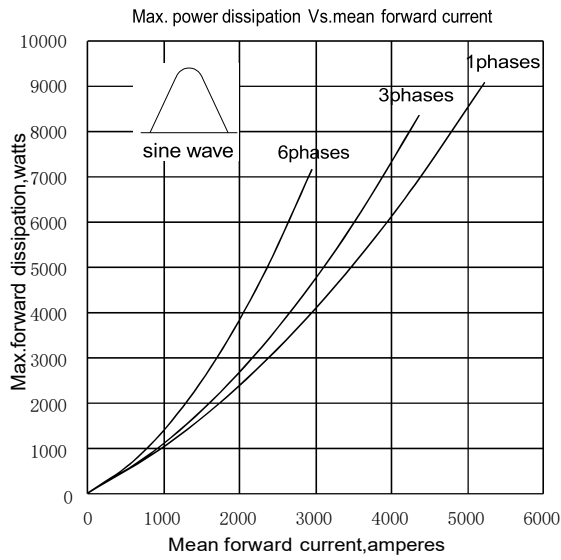


Fig.3

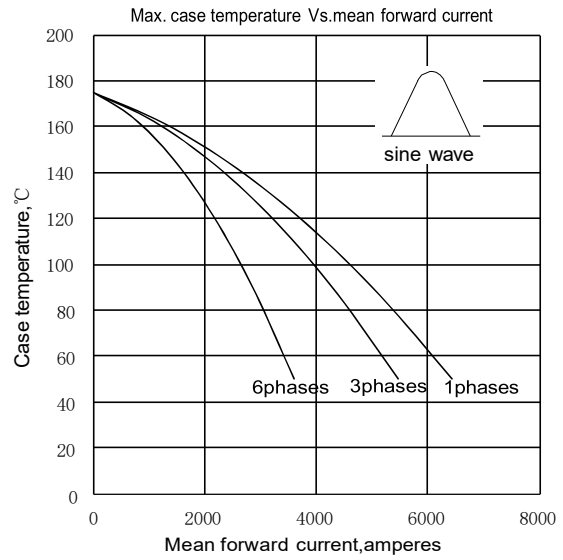


Fig.4

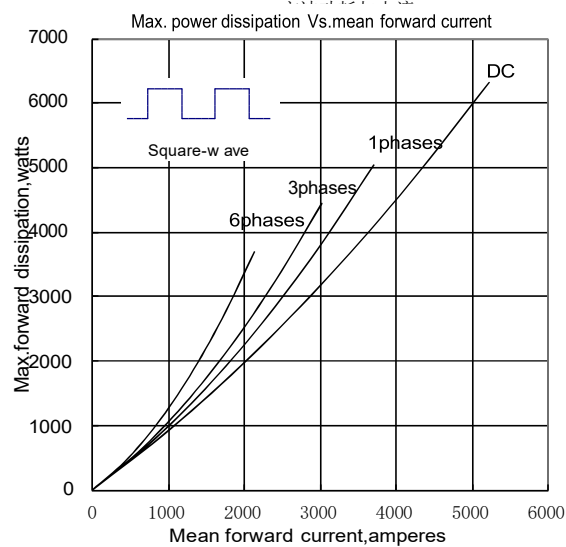


Fig.5

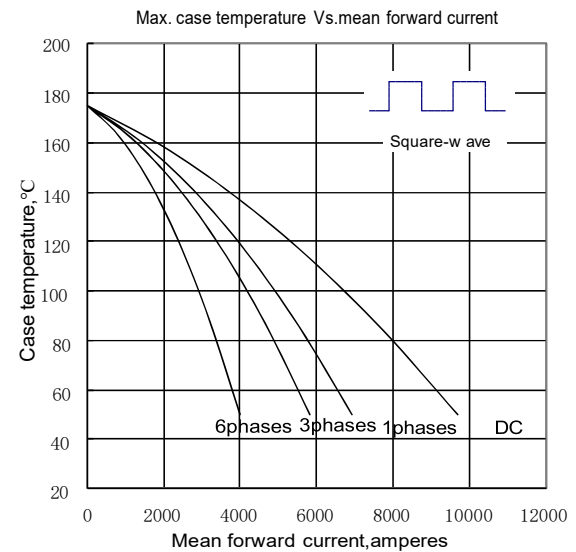


Fig.6

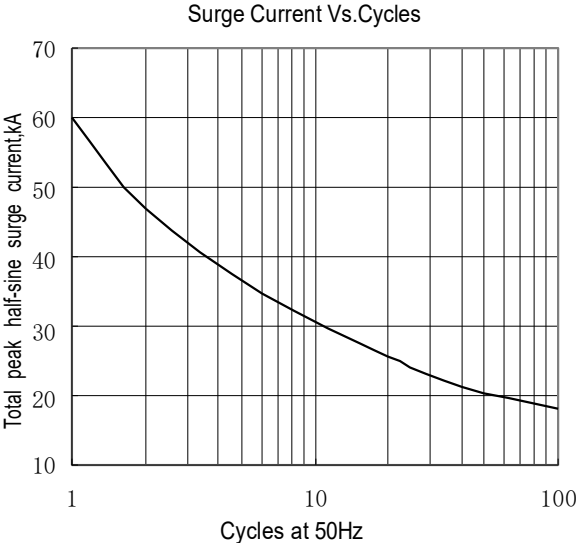


Fig.7

Outline:

